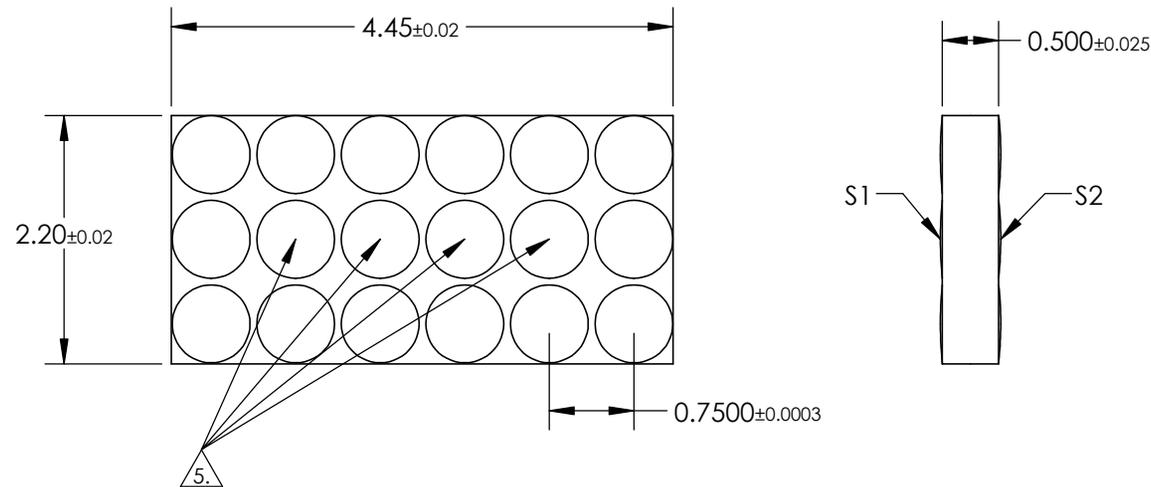
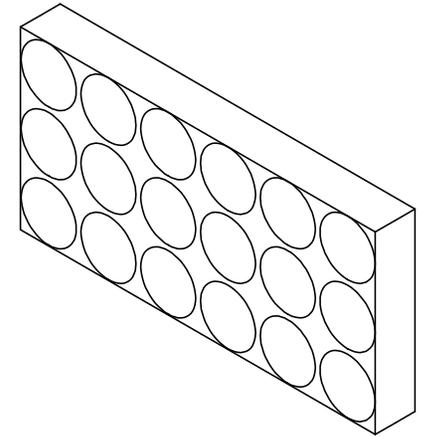


NOTES:

1. SUBSTRATE:
Silicon
2. COATING (APPLY ACROSS COATING APERTURE):
S1 & S2: R(AVG) $\leq 0.5\%$ @ 1250 - 1620
3. WORKING DISTANCE (mm):
1.202
4. MODE FIELD DIAMETER (mm):
Source: 0.0092
Target: 0.25

5. ACTIVE LENSES CENTERED ON SUBSTRATE

6. ROHS: COMPLIANT



SPECIFICATIONS SUBJECT TO CHANGE WITHOUT NOTICE
DIMENSIONS ARE FOR REFERENCE ONLY

**FOR INFORMATION ONLY:
DO NOT MANUFACTURE
PARTS TO THIS DRAWING**

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THIRD ANGLE PROJECTION		TITLE	4.45 x 2.20mm, 3.378 ROC, 750 μ m Pitch, Silicon, 1 x 4 Linear Microlens Array	
ALL DIMS IN	mm	DWG NO	21180	SHEET 1 OF 1